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Vishay Semiconductors

# High Speed Infrared Emitting Diodes, 890 nm, **Surface Emitter Technology**





#### **DESCRIPTION**

As part of the SurfLight™ portfolio, the VSMY2890 series are infrared, 890 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

### **APPLICATIONS**

- · Automotive sensors
- Photointerrupters
- Emitter source for proximity sensors
- IR illumination

### **FEATURES**

 Package type: surface-mount · Package form: GW, RGW

• Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8

AEC-Q101 qualified

• Peak wavelength:  $\lambda_p = 890 \text{ nm}$ 

• Angle of half intensity:  $\varphi = \pm 10^{\circ}$ 

• Suitable for high pulse current operation

· Terminal configurations: gullwing or reverse gullwing

 Package matches with detector VEMD2500X01 series

Floor life: 4 weeks, MSL 2a, according to J-STD-020

· Material categorization: for definitions of compliance please see www.vishav.com/doc?99912









PRODUCT SUMMARY					
COMPONENT	$I_e$ (mW/sr) at $I_F$ = 100 mA	φ <b>(°)</b>	λ <sub>P</sub> (nm)	t <sub>r</sub> (ns)	
VSMY2890RGX01	135	± 10	890	15	
VSMY2890GX01	135	± 10	890	15	

#### Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMY2890RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing	
VSMY2890GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing	

· MOQ: minimum order quantity



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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	А	
Power dissipation		P <sub>V</sub>	190	mW	
Junction temperature		T <sub>j</sub>	100	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C	
Soldering temperature	According to Fig. 9, J-STD-020	T <sub>sd</sub>	260	°C	
Thermal resistance junction-to-ambient	JESD51	R <sub>thJA</sub>	250	K/W	

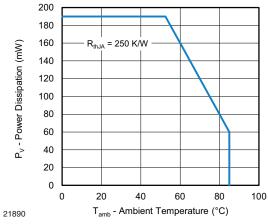


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

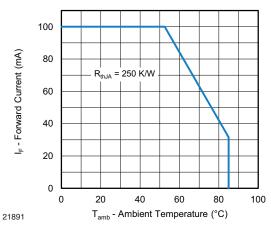


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$V_{F}$	-	1.7	1.9	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	V <sub>F</sub>	-	2.8	-	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>	-	-2.0	-	mV/K
Reverse current		I <sub>R</sub>	Not designed for reverse operation μA		μΑ	
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}, E = 0 \text{ mW/cm}^2$	CJ	-	60	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	50	135	175	mW/sr
nation intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	l <sub>e</sub>	-	1000	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe	-	55	-	mW
Temperature coefficient of radiant power	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>	-	-0.12	-	%/K
Angle of half intensity		φ	-	± 10	-	0
Peak wavelength	I <sub>F</sub> = 100 mA	$\lambda_{p}$	870	890	910	nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ	-	35	-	nm
Temperature coefficient of λ <sub>p</sub>	I <sub>F</sub> = 100 mA	TKλ <sub>p</sub>	-	0.3	-	nm/K
Rise time	I <sub>F</sub> = 100 mA, 10 % to 90 %	t <sub>r</sub>	-	15	-	ns
Fall time	I <sub>F</sub> = 100 mA, 10 % to 90 %	t <sub>f</sub>	-	15	-	ns

### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

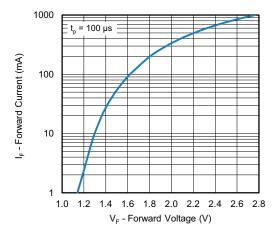


Fig. 3 - Forward Current vs. Forward Voltage

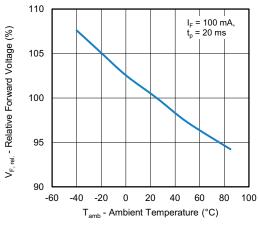


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

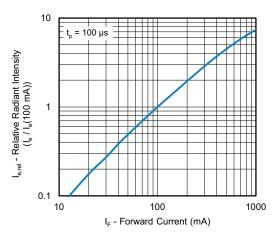


Fig. 5 - Relative Radiant Intensity vs. Forward Current

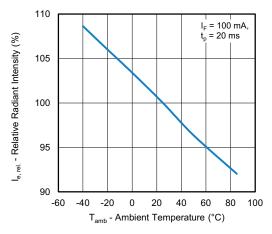


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

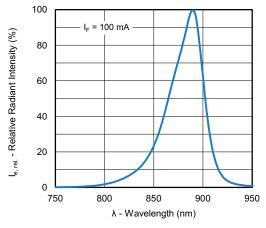


Fig. 7 - Relative Radiant Intensity vs. Wavelength

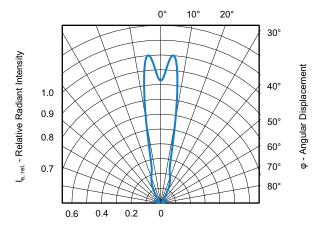


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

# VSMY2890RGX01, VSMY2890GX01

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### **SOLDER PROFILE**

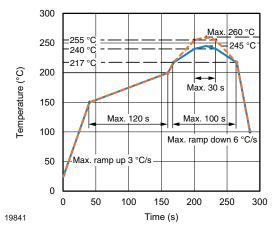


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

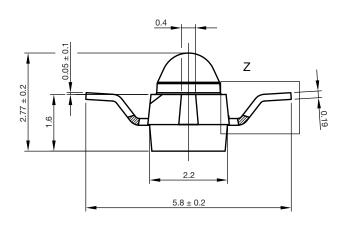
Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

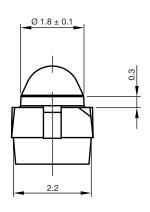
Moisture sensitivity level 2a, according to J-STD-020.

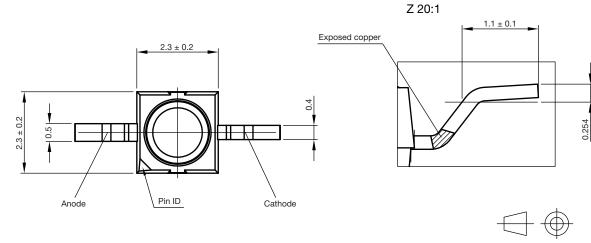
#### **DRYING**

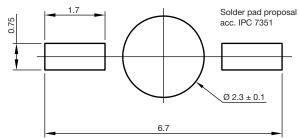
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D or label. Devices taped on reel dry using recommended conditions 192 h at 40  $^{\circ}$ C (+ 5  $^{\circ}$ C), RH < 5  $^{\circ}$ M.

### PACKAGE DIMENSIONS in millimeters: VSMY2890RGX01



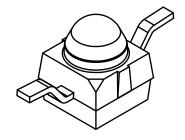






technical drawings according to DIN specifications

Not indicated tolerances ± 0.1

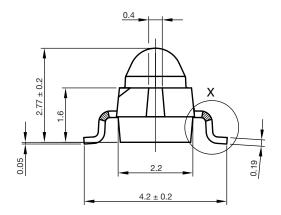


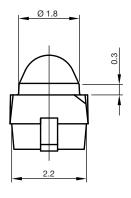
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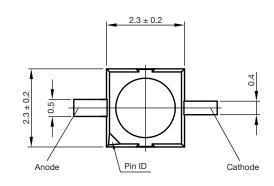
Issue: 1; 18.03.10

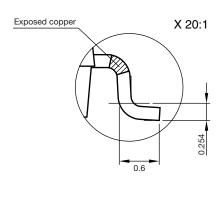
22100

### PACKAGE DIMENSIONS in millimeters: VSMY2890GX01

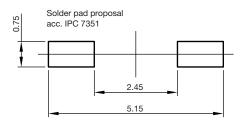




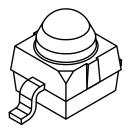








Not indicated tolerances  $\pm$  0.1



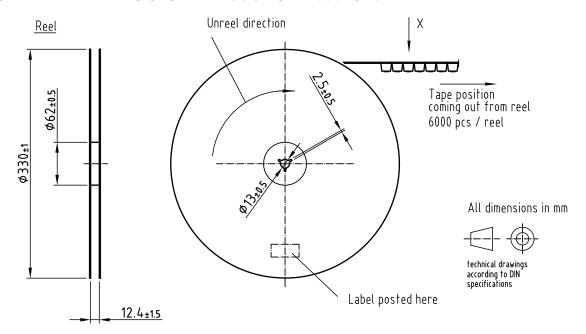
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Issue: 1; 18.03.10

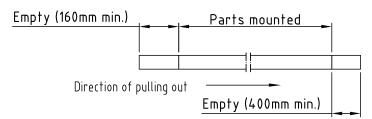
22099



### TAPING AND REEL DIMENSIONS in millimeters: VSMY2890RGX01

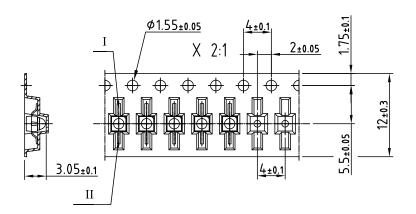


### Leader and trailer tape:



### Terminal position in tape

Device	Lead I	Lead II	
VEMT 2000	Collector Emitte		
VEMT 2500	Collector	Emiliei.	
VEMD 2000			
VEMD 2500			
VSMB 2000	Cathode	Anode	
VSMG 2000	Carriode	Alloue	
VSMF 2890 RG			
VSMB 294008 RG			
VSMY 2xxx			
	Anode	Cathode	
VSMF 288011 RG			

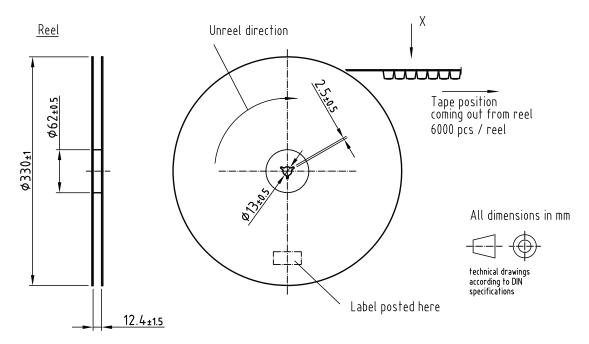


Drawing refers to following types: Reel dimensions and tape see table

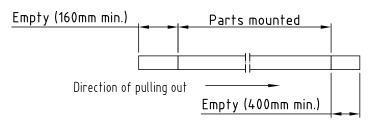
Drawing-No.: 9.800-5100.01-4 Issue: preliminary, 11.07.19



### TAPING AND REEL DIMENSIONS in millimeters: VSMY2890GX01

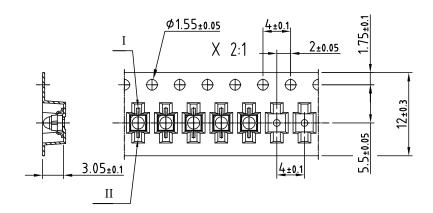


### Leader and trailer tape:



### Terminal position in tape

Device	Lead I	Lead II	
VSMB 2020			
VSMG 2020			
VEMD 2020	C-44.4.	A = d .	
VEMD 2520	Cathode	Anode	
VSMF 2890 G			
VSMB 294008 G			
VEMT 2020	C . II	F=:44	
VEMT 2520	Collector	Emitter	
VSMY 2xxx			
	Anode	Cathode	
VSMF 288011 G			



Drawing refers to following types: see table

Drawing-No.: 9.800-5091.01-4 Reel dimensions and tape Issue: preliminary, 11.07.19



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